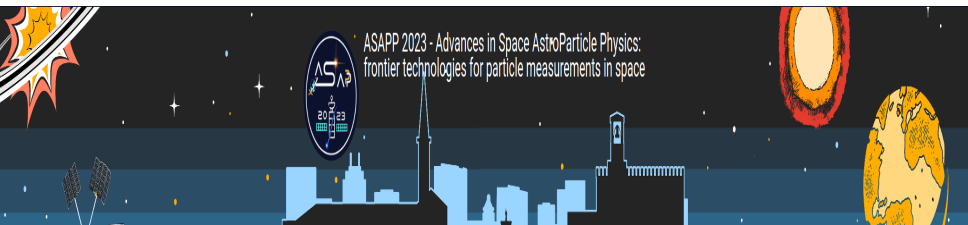
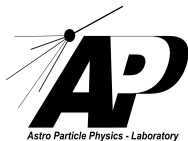


Development of LGADs for the 4D tracking of charged particles in Space Experiments

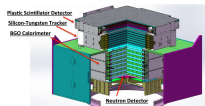
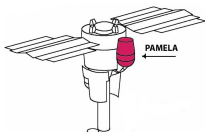
Ashish Bisht, G. Borghi, M. Boscardin, L. Cavazzini,
M. Centis Vignali, O. Hammad Ali, F. Ficorella. G. Paternoster



UNIVERSITY
OF TRENTO



Particle tracking in space experiments for Cosmic Rays



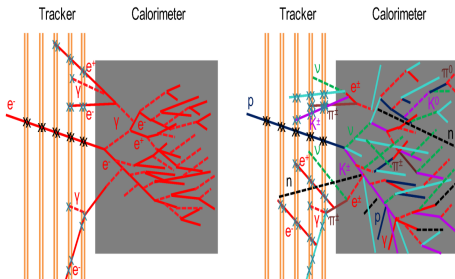
- ▶ Discrimination of charged particles
→ Magnetic spectrometers
- ▶ Tracking planes based on Silicon μ -strip detectors
- ▶ Magnetic field used to bend the trajectory
→ reconstruct momentum and particle charge
- ▶ γ -rays measurements
- ▶ High-density material is used for pair production
- ▶ Tracking planes are inserted between the conversion foils
- ▶ Tracking planes based on Silicon μ -strip detectors
→ reconstruct the vertex of the incoming photon and its direction.

Future missions → HERD, ALADINO, AMS-100

Objective → probe higher energy cosmic rays, improved sensitivity

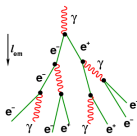
Time resolving tracking in space experiments

- Identification of back-scattered hits from calorimeters
- Ghost hits in “Si-MicroStrip” detectors
- Time-of-flight (ToF) measurement
- Improved e/p identification

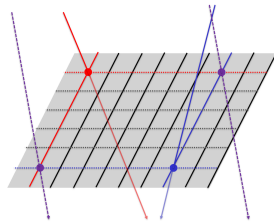
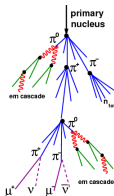


$$\frac{\delta M}{M} = \frac{\delta p}{p} \oplus \gamma^2 \left(\frac{\delta \beta}{\beta} \right)$$

em cascade



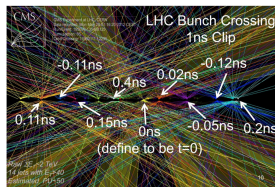
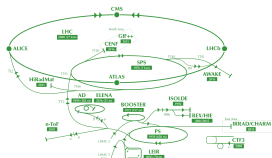
hadronic cascade



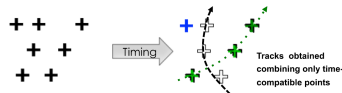
- d and anti-d
- $^3\text{He}/^4\text{He}$

4D tracking

4D tracking is referred to assigning a space and a time coordinate to a hit



H. Sadrozinski et al. Rept. Prog. Phys. 81 (2018) 026101 [↗](#)



Timing for event reconstruction:

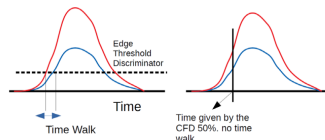
- ▶ Dedicated timing layer in a single point
- ▶ Timing at some points along the track
- ▶ Timing at each point along the track

Is it possible to build a detector with excellent time and position resolution?

→ Spatial resolution [10's of μm] + timing resolution [~ 10 ps]

Time resolution of time tagging detectors

$$\sigma_t^2 = \sigma_{\text{timewalk}}^2 + \sigma_{\text{Landau}}^2 + \sigma_{\text{TDC}}^2 + \sigma_{\text{Jitter}}^2$$



► Time walk:

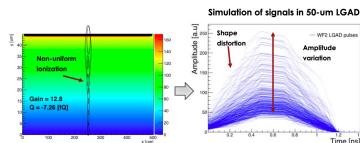
→ minimized by using Constant Fraction Discriminator (CFD) for time reference

► Landau noise: non-uniformity in the energy deposited per unit length

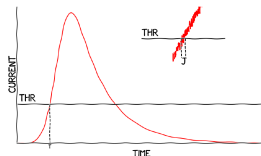
→ reduced for **thinner sensors** (50, 35 μm)

► TDC: resolution of the TDC ($\text{bin}/\sqrt{12}$)

► Jitter: proportional to $\sigma_N / \frac{dV}{dt}$ → reduced by increasing SNR with gain.

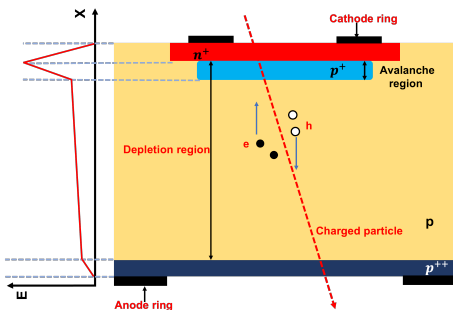


N. Cartiglia et al. PSD12 (2021) 



$$\sigma_j = \sigma_n / \frac{dI}{dt}$$

Low Gain Avalanche Detector (LGAD)



- ▶ Silicon detectors with charge multiplication
- ▶ Gain layer provides a high-field region
- ▶ Radiation hard (10^{15} neq/cm²)
- ▶ Low Noise (low shot noise)

▶ Improved SNR: 5-10 times better than current PIN detectors

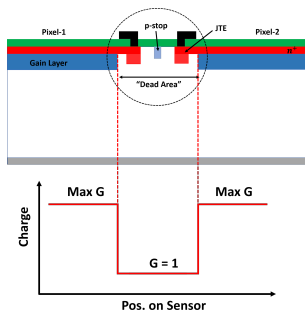
▶ Good timing resolution:

$$\sigma_t = 30 \text{ ps} \rightarrow 50 \text{ } \mu\text{m thick LGADs (1.3} \times \text{1.3 mm}^2)$$

▶ No-gain region $\sim 30\text{-}80 \text{ } \mu\text{m}$

A. Bisht et. al., Characterization of Novel trench-isolated LGADs for 4D tracking

\rightarrow No-gain region $\sim 3 \text{ } \mu\text{m}$



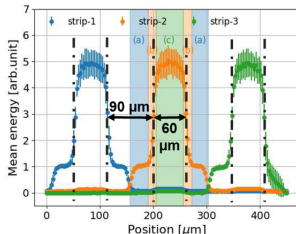
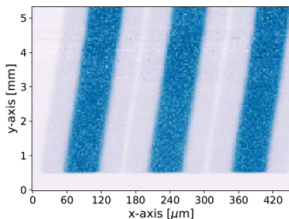
- ▶ Segmentation in LGADs:
 - Junction Termination Extensions (JTEs)
 - p-Stop, and virtual Guard-Rings
- ▶ Pixel border is a dead region.
- ▶ The no-gain width depends on:
 - technology (photolithography) constraints
 - physical limits (maximum E fields) to fulfill operational requirements (VBD)
- ▶ Intrinsic limit in reducing the inter-pad region (*Early edge breakdown*).

Standard LGADs \rightarrow $\left\{ \begin{array}{l} \text{Good timing resolution} \\ \text{Poor spatial resolution} \end{array} \right.$

$$\text{Fill Factor} = \text{Area}_{\text{gain}} / \text{Area}_{\text{total}}$$

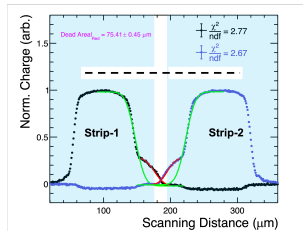
Measurements with a micro-focused X-ray beam
(width $\sim 2 \mu\text{m}$, 20 keV)

- ▶ LGAD μ -strip sensor (146 μm pitch)
- ▶ Nominal gain region: 80 μm \rightarrow Nominal FF: 55%
- ▶ Measured FF: 40%

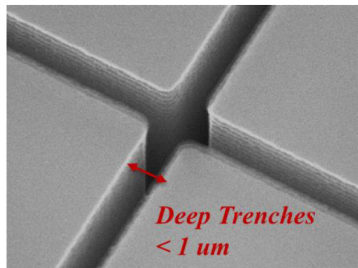
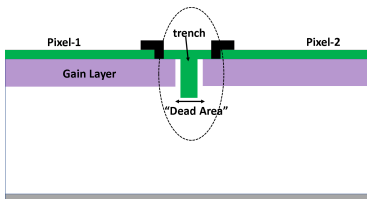


Measurements with a
pulsed laser.

- ▶ 180 μm pitch
- ▶ Nominal FF: 63%
- ▶ Measured FF: 58%



Fill Factor: solution?



- ▶ New LGAD technology ↗ :
 - **JTE and p-stop** → **trench**
 - Trenches → drift/diffusion barrier

- ▶ Dead region is significantly reduced

- ▶ The trenches are $< 1 \mu\text{m}$ wide and few microns deep.

- ▶ Trenches are filled with SiO_2

TI – LGADs → $\left\{ \begin{array}{l} \text{Good timing resolution} \\ \text{Smaller gain – loss region} \\ \text{Improved spatial resolution} \end{array} \right.$

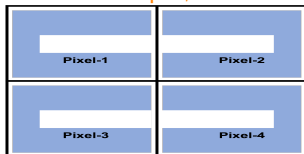
New batch fabricated under the RD50 collaboration ↗

G. Paternoster et al., "Trench-Isolated Low Gain Avalanche Diodes" ↗

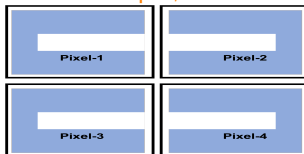


TI-LGADs: no-gain region width

250 × 375 μm, 1 trench



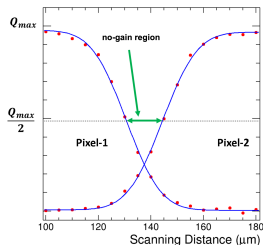
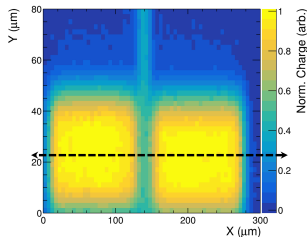
250 × 375 μm, 2 trenches



$$f(x) = \left[\text{Erf} \left(\pm \frac{x - c_1}{c_2} \right) + 1 \right] \times c_3 + c_4,$$

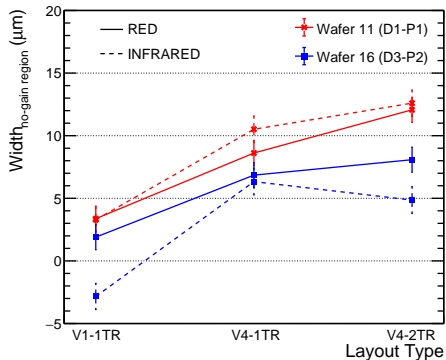
$$\text{Erf}(x) = \frac{2}{\sqrt{\pi}} \times \int_0^x e^{-t^2} dt$$

charge map @ -200 V



V1-1TR, V4-1TR, V4-2TR

TI-LGADs: no-gain region width

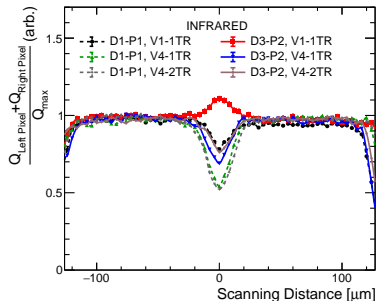
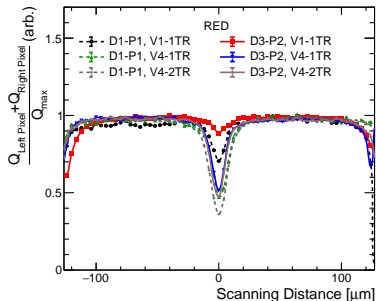


40 μm → 3 μm

- ▶ Negative width of no-gain region is measured in W16, V1-1TR layout (See next Slide)
- ▶ Wafer 16, V4-2TR → significant reduction of no-gain region width

- ▶ No-gain region width < 15 μm
→ Better compared to all standard LGADs
- ▶ Width of no-gain region for V1-1TR layout is less than 5 μm for both wafers
V1-1TR → Highest Fill-Factor
- ▶ Wafer 16 has lower no-gain region width compared to wafer 11
- ▶ Red laser does not account for the change in field in the bulk due to trench

TI-LGADs: sum of pixel charge



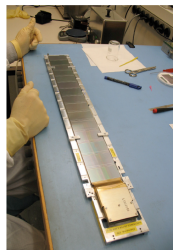
- ▶ IR Laser → W16: charge enhancement close to the trench region (higher gain) for V1-1TR, V4-2TR.
- ▶ Higher gain in trench region artificially reduces width of the no-gain region.

TI-LGADs → to achieve high FF.

Large strip sensors using TI-LGADs.

Space experiment requirements

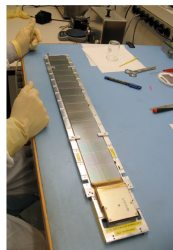
- ▶ Large area to cover $\rightarrow O(m^2)$
- ▶ Low Earth Orbit Experiments
 \rightarrow *Radiation is not an issue*
- ▶ Rate is not as high as in HEP
- ▶ Power constraint
 \rightarrow *Reduce the number of channels*
- ▶ **Timing (~ 50 - 100 ps) is desired**



- ▶ “Typical” Silicon sensor
 - \rightarrow Strips ($100\ \mu\text{m}$ pitch)
 - \rightarrow 60-100 cm long
 - $\rightarrow \sim 1\ \text{cm}^2$

Space experiment requirements

- ▶ Large area to cover $\rightarrow O(m^2)$
- ▶ Low Earth Orbit Experiments
 \rightarrow *Radiation is not an issue*
- ▶ Rate is not as high as in HEP
- ▶ Power constraint
 \rightarrow *Reduce the number of channels*
- ▶ **Timing (~ 50 - 100 ps) is desired**

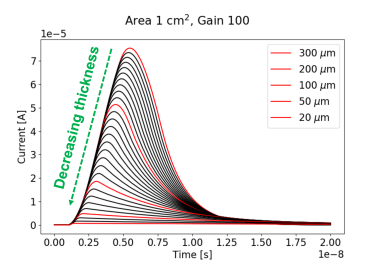
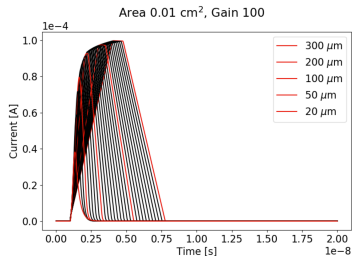


- ▶ “Typical” Silicon sensor
 \rightarrow Strips ($100 \mu m$ pitch)
 \rightarrow 60-100 cm long
 $\rightarrow \sim 1 \text{ cm}^2$

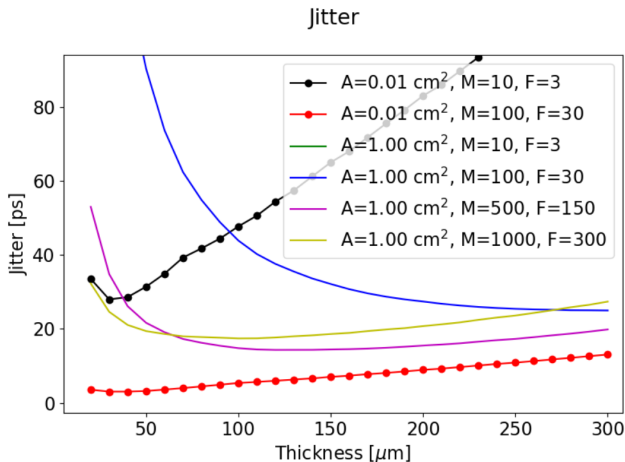
Scaling LGAD channel size to 1 cm^2

Capacitance?
Time resolution?

- ▶ LTspice simulation
- ▶ Sensor capacitance
- ▶ No Landau fluctuations (uniform charge deposition)
- ▶ Saturated velocities
- ▶ Total Noise = Amplifier \oplus Sensor



[M. Centis Vignali et al. VCI (2022)]

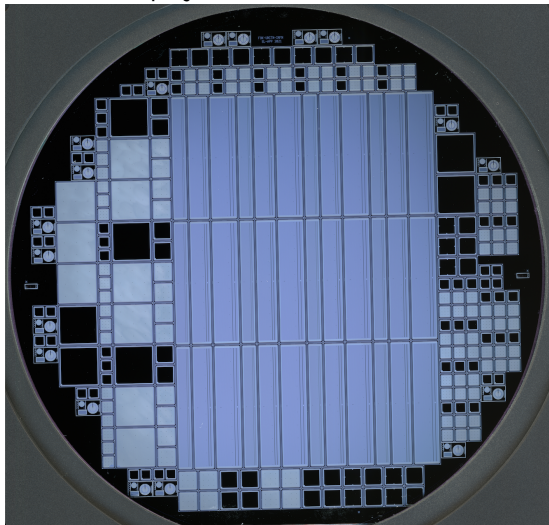


[M. Centis Vignali et al. VCI (2022)]

LGAD thickness $> 100 \mu\text{m}$ and gain ≈ 100

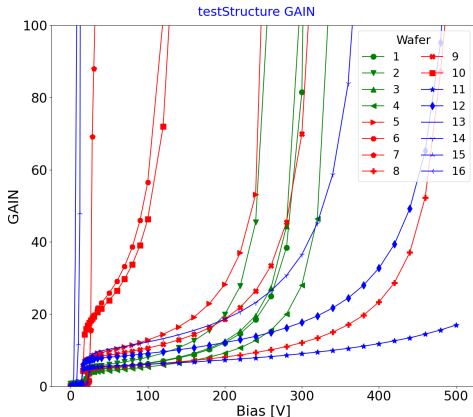
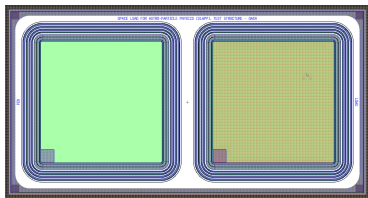
Production of new LGAD sensors under INFN project

- ▶ Optimized for large areas
- ▶ Pad and strip sensors
- ▶ Strips: 100 μm , 150 μm , 200 μm pitch
- ▶ Active thickness: 50 μm , 100 μm , 150 μm thick
- ▶ Gain implant dose and energy optimized for high gain using TCAD
- ▶ Signal propagation



Gain: using IR LED

- ▶ $T = 24^\circ$ with illumination.
- ▶ $50\ \mu\text{m}$
- ▶ $100\ \mu\text{m}$
- ▶ $150\ \mu\text{m}$



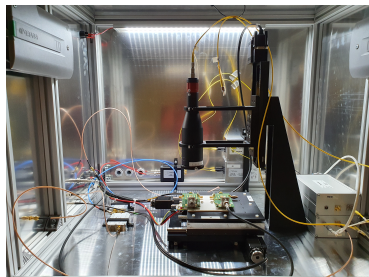
- ▶ value of gain highly depends on the dose and energy of the implant
- ▶ less steep curves for better operating voltage

Experimental Setup: Transient Current Technique (TCT)

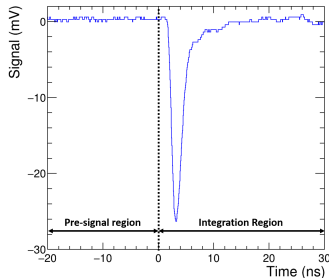
Particulars TCT setup:

- ▶ Infra-Red (1060 nm) and Red (600 nm) pulsed Laser
→ 10-15 μm spot
- ▶ X/Y translation stage (0.8 μm precision)
→ precise inter-pixel scan and DUT maps
- ▶ DAQ: 2.5 GHz, 20 GS/s
- ▶ Beam Monitor: normalization
- ▶ Collected charge is given as:

$$Q = \int_{t_0}^{t_f} I(t) dt$$



Waveform @ -200V



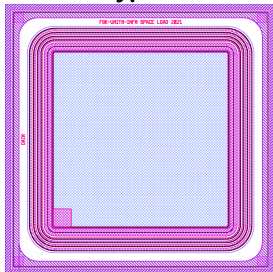
► Pad active area:

- A (6.25 mm^2)
- B (25 mm^2)
- C (100 mm^2)

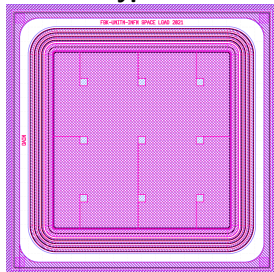
► Pad types:

- **Type-0:** Metal frame
- **Type-1:** Fully Metallized, Contacts at the edge of the active area
- **Type-2:** Fully Metallized, Contacts covers all active area

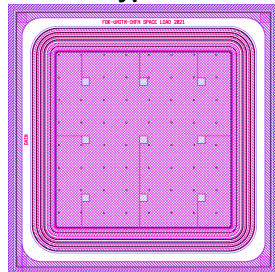
Type-0



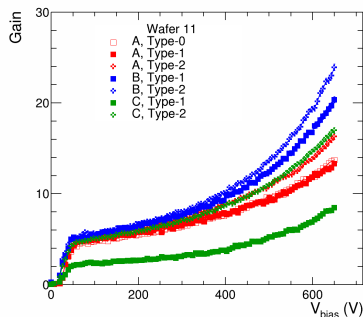
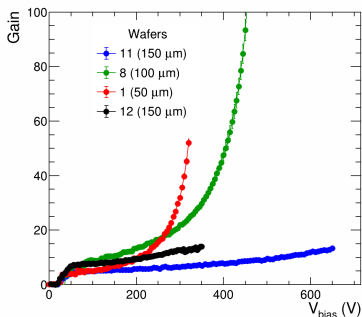
Type-1



Type-2



Gain: using TCT setup

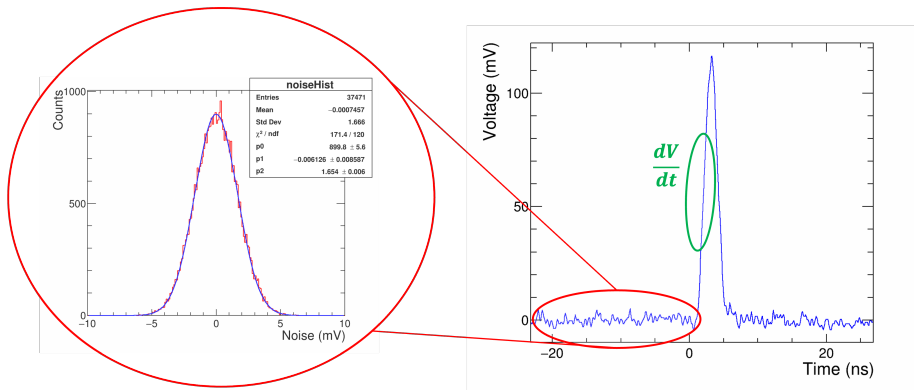


$$Gain = \frac{Charge_{LGAD}}{Charge_{PIN}}$$

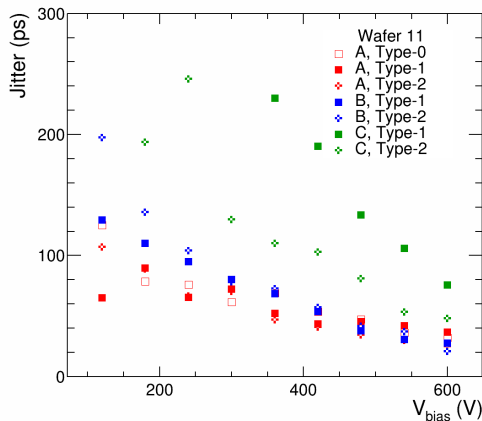
- ▶ Laser Intensity: 1 MIP
- ▶ Low bias voltage: gain value is similar
- ▶ High bias voltage: gain value has a spread of about 20%
- ▶ One device show low gain values compared to others

$$\sigma_{jitter} = \frac{\text{Noise } (N)}{\text{Slew rate } (dV/dt)}$$

- ▶ Measurement (no averaging in Oscilloscope) → Noise estimation
- ▶ Measurement (256 averages in Oscilloscope) → Slew rate estimation



First Jitter measurements of 1 cm² LGADs



- ▶ Laser intensity: 1 MIP
- ▶ substrate thickness: 150 μm
- ▶ pad sizes:
 - A (6.25 mm²)
 - B (25 mm²)
 - C (100 mm²)
- ▶ Metallization:
 - metal frame
 - fully metallized
 - ◆ fully metallized + contact openings

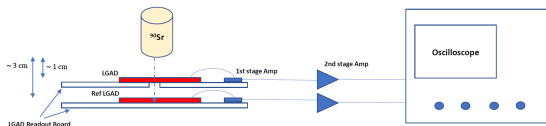
$\sigma_{Jitter} < 50$ ps for an LGAD 1 cm² @ 600 V

- ▶ Include timing measurement for each hit/track in the silicon tracker
- ▶ LGADs → suitable candidate based on the timing performance for HEP experiments
- ▶ TI-LGADs show a no-gain region less than 5 μm (high Fill Factor).
- ▶ Increase active area of the LGADs → Gain $\sim \mathcal{O}(100)$ and Thickness (>100 μm)
- ▶ Increase the gain to about 100 for reduced Jitter values
- ▶ Space LGADs production optimized to study large area LGADs
- ▶ $\sigma_{\text{Jitter}} < 50$ ps → 100 mm^2 active area
- ▶ $\sigma_{\text{Jitter}} \sim 20$ ps → 6 mm^2 active area.

- ▶ Ongoing characterization of space LGADs → timing resolutions
- ▶ Possible beam test in future
- ▶ Space qualification test

Two new projects with LGADs for space applications

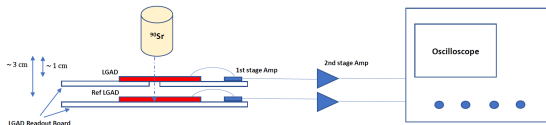
- ▶ INFN-FBK: ADA-5D
- ▶ PRIN: Pentadimensional Tracking Space Detector -PTSD
- ▶ PNRR: LGADs for TOF measurements



- ▶ Ongoing characterization of space LGADs → timing resolutions
- ▶ Possible beam test in future
- ▶ Space qualification test

Two new projects with LGADs for space applications

- ▶ INFN-FBK: ADA-5D
- ▶ PRIN: Pentadimensional Tracking Space Detector -PTSD
- ▶ PNRR: LGADs for TOF measurements



Thank you for your attention

